Keysight Technologies
Sequential Shunt Regulation
Regulating Satellite Bus Voltages

Application Note
Sequential shunt regulation is widely used for regulating satellite bus voltages. A simplified sequential shunt configuration is shown in Figure 1.

The Keysight Technologies, Inc. E436xA modular solar array simulator (SAS) is ideal for this type of application. Operating in this configuration, the SAS output current either flows into the load or into the shunt control FETs. The shunt control FET will be referred to as “the shunt” or “the switch” for the remainder of this paper.

Figure 2 shows a typical solar array I-V curve. As an example, let’s assume operation at the maximum power point. When the shunt is open, the current to the load will be $I_{mp}$ (current at the maximum power point). When the shunt is closed, the current in the shunt is $I_{sc}$ (short circuit current). Figure 3 shows the output waveforms from one SAS. The output current of the SAS is basically constant because the difference between $I_{mp}$ and $I_{sc}$ is usually small; however, the voltage changes from near zero with a short (switch on) to $V_{mp}$ (switch off).

Figure 1. Example of a simplified sequential shunt regulation configuration
If the bus voltage \( V_{mp} \), then the output power delivered to the bus is \( (1-D) (N) (P_{mp}) \) where: \( D \) = "on" duty cycle of the shunt FET, \( N \) = number of SAS supplies, \( P_{mp} \) = maximum power point. To satisfy the power demands of the power system of the satellite, the output voltage of the SAS has to rise within about 1 to 10 \( \mu s \) when the shunt is opened and the operating point changes from the short circuit point to the operating load point on the curve. The E436xA's low output capacitance (<50 nF) allows this fast rise time and also limits the turn on switching losses in the shunt switch. The E436xA can handle switching frequencies up to 50 kHz. Figure 3 shows the output voltage and current of the E4362A when the shunt switches at 50 kHz with shunt FET rise and fall times of about 1 \( \mu s \). For this test, the E4362A is in SAS mode (refer to data sheet) and the I-V curve is defined by these four parameters: \( I_{sc} = 5.00 \) A, \( I_{mp} = 4.75 \) A, \( V_{mp} = 120 \) V and \( V_{oc} = 130 \) V. The load is about 42 ohms. (Note that with these settings and the duty cycle used, the operating point is not the maximum power point.) The wire inductance between the SAS output and the shunt switch is very low. As the inductance increases, the voltage overshoot on the output voltage will increase, but will be limited by fast acting internal clamp circuits. The overshoot and undershoot in the current (Figure 3) are due to the internal output snubber, as part of the output capacitance, charging and discharging. Note that in Figure 1, the bus capacitor across the battery is required to smooth the bus voltage and current, lowering the ripple.
Figure 1 shows diodes in series with each output of the SAS (after the shunt). These diodes isolate the supplies so that when one shunt is on, the bus voltage and other SAS outputs are not pulled low. The diodes should have very fast recovery time (or they should be Schottky diodes); otherwise the power dissipation in the diode and the shunt FET will be high. Higher levels of noise will also occur if slow diodes are used, or if the FET rise and fall times are too fast. The latter can be controlled by adjusting the FET gate resistor. A snubber (RC) across the diodes may help reduce the switching noise and voltage overshoots. A heatsink may be needed to keep the FET or diode cool and within its temperature ratings.

Voltage and current ratings of the shunt switch are determined by the Voc and Isc parameters. The heatsink design for the switch will depend on the switching frequency, the duty cycle, and the output current. Higher switching frequency and higher duty cycle (“on” time) will increase the power dissipation in the shunt FET.

Sometimes, more current (and power) is required than is available from a single output. In cases like this, SAS outputs can be placed in parallel for more current capability. The E436xA SAS outputs can be used in either direct-parallel or auto-parallel, however, for sequential shunt applications, direct-parallel is recommended as shown in Figure 4. An E436xA SAS can be configured to have its outputs “grouped” which simplifies the programming of the outputs by treating the two outputs as one output from a programming perspective. Programming commands will then need to be sent to only a single output instead of having to send commands to each of the paralleled outputs individually.

When using a sequential shunt configuration, the number of strings is determined by the total power required. When using the E436xA, strings may be added or subtracted as necessary for the particular application. Each string is programmable over LAN, GPIB, or USB using SCPI (Standard Commands for Programmable Instruments). The E436xA also comes with the Keysight 14360A System Control Tools software which is used to simplify the control of a large number of solar array simulator outputs in a system of E4360A SAS’s.
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